STK5F1U3C2D-E

Advance Information Intelligent Power Module (IPM) 600 V, 30 A



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Overview

This "Inverter Power IPM" is highly integrated device containing all High Voltage (HV) control from HV-DC to 3-phase outputs in a single DIP module (Dual-In line Package). Output stage uses IGBT / FRD technology and implements Under Voltage Protection (UVP) and Over Current Protection (OCP) with a Fault Detection output flag. Internal Boost diodes are provided for high side gate boost drive.

Function

- Single control power supply due to Internal bootstrap circuit for high side pre-driver circuit
- All control input and status output are at low voltage levels directly compatible with microcontrollers
- Cross conduction prevention
- Externally accessible embedded thermistor for substrate temperature measurement
- The level of the over-current protection current is adjustable with the external resistor, "RSD"

Certification

• UL1557 (File Number : E339285)

Specifications

Absolute Maximum Ratings at Tc = 25°C

Parameter	Symbol	Remarks	Ratings	Unit
Supply voltage	Vcc	P to N, surge < 500 V *1	450	V
Collector-emitter voltage	VCE	P to U, V, W or U, V, W to N	600	V
Output current	lo	P, N, U, V, W terminal current	±30	^
		P, N, U, V, W terminal current, Tc = 100°C	±15	A
Output peak current	lop	P, N, U, V, W terminal current, PW = 1 ms	±49	А
Pre-driver supply voltage	VD1, 2, 3, 4	VB1 to VS1, VB2 to VS2, VB3 to VS3, V_DD to V_SS $\ ^*\!2$	20	V
Input signal voltage	VIN	HIN1, 2, 3, LIN1, 2, 3	–0.3 to V_{DD}	V
FAULT terminal voltage	VFAULT	FAULT terminal	-0.3 to V _{DD}	V
Maximum loss	Pd	IGBT per channel	56.8	W
Junction temperature	Tj	IGBT,FRD	150	°C
Storage temperature	Tstg		-40 to +125	°C
Operating temperature	Тс	IPM case	-20 to +100	°C
Tightening torque	MT	A screw part at use M4 type screw *3	1.17	Nm
Withstand voltage	Vis	50 Hz sine wave AC 1 minute *4	2000	VRMS

Reference voltage is N terminal = V_{SS} terminal voltage unless otherwise specified.

*1: Surge voltage developed by the switching operation due to the wiring inductance between the P and N terminals.

*2 : Terminal voltage : VD1 = VB1 to VS1, VD2 = VB2 to VS2, VD3 = VB3 to VS3, VD4 = V_{DD} to V_{SS}.

*3 : Flatness of the heat-sink should be 0.25 mm and below.

*4 : Test conditions : AC 2500 V, 1 s.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

This document contains information on a new product. Specifications and information herein are subject to change without notice.

ORDERING INFORMATION

See detailed ordering and shipping information on page 14 of this data sheet.

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Electrical Characteristics at Tc = 25°C, VD1, VD2, VD3, VD4 = 15 V

Devenuetor	Symbol	Conditions		Test circuit	Ratings		l la it	
Parameter					Min.	Тур.	Max.	Unit
Power output section								
Collector to emitter cut-off current	ICE	V _{CE} = 600 V		Fig 1	-	-	100	μA
Bootstrap diode reverse current	IR(BD)	VR(BD) = 600 V		1.9.1	-	-	100	μA
Collector to emitter saturation	V _{CE} (sat)	Ic = 30 A	Upper side	Fig.2	-	1.7	2.5	V
			Lower side		-	2.2	3.1	
voltage		lc = 15 A, Tj = 100°C	Upper side		-	1.4	-	
			Lower side		-	1.7	-	
Diada farward valtara	VF	IF = 30 A	Upper side	- Fig.3	-	1.8	2.7	V
			Lower side		-	2.3	3.1	
Diode forward voltage		IF = 15 A, Ti = 100°C	Upper side		-	1.45	-	
			Lower side		-	17	-	
	Ai-c(T)	IGBT	201101 0.00		_	1.8	_	°C/W
Junction to case thermal resistance		EWD				2.3		°C/M
Control (Pre-driver) section	0j-0(D)	TWD		_		2.0	_	0/11
Pre-drive power supply consumption		VD1, 2, 3 = 15 V			-	0.05	0.4	mA
current	ID	VD4 = 15 V		Fig.4	-	10	4 0	
High level input voltage	Vin H		1	-	25	-	-	
Low level input voltage	Vin I	LIN1, LIN2, LIN3	, to Vss	-	-	-	0.8	v
		VIN = +2.2.V				100	195	Δ
		VIN = 0 V				100	100	μΑ
Protection section	'IIN-	VIII - 0 V				<u> </u>		μΛ
Over-current protection electric		DW = 100 up BS	D = 0 O	Fig 5	27		40	•
current	130	FW = 100 μs, κδ	D = 0 12	Fig.5	37	-	49	A
V_{DD} and V_{Bx} supply undervoltage	V _{ddUV+}				10.6	11.1	11.6	v
positive going input threshold	VBxUV+							
V_{DD} and V_{Bx} supply undervoltage	VddUV-				10.4	10.9	11.4	V
	VBxUV-							
vDD and vBx supply undervoltage	VddUVH Vp., IN/II					0.2		V
FALIL T terminal input electric current		VEALUT = 0.1 V		_	1	15	-	mΑ
FALILT clearance delay time	FLTCLR	From time fault co	ndition clear	_	18	-	80	ms
	TETOER			_	10	_	00	1113
Thermistor for substrate temperature monitor	Rt	and VSS(20) term	en the TH(18) ninals	-	90	-	110	kΩ
Switching character		00()				<u> </u>	i	
	tON	lo = 30 A, Inductive load		1		0.8	15	116
Switching time	tOFF				_	1.0	2.0	μ3
Turne and an italian a large				-	-	740	2.0	μs
Turn-on switching loss	Eon	lo = 30 A, V _{CC} = 300 V,		Fig.6	-	710 570	-	μJ
Total switching loss	Etot	VD = 15 V, L = 690 µH			-	1280	-	uJ
Turn-on switching loss	Eon	lo = 15 A, V _{CC} = 300 V,			-	360	-	μJ
Turn-off switching loss	Eoff	VD = 15 V, L = 690 μH,			-	460	-	μJ
Total switching loss	Etot	Tc = 100°C			-	820	-	μJ
Diode reverse recovery energy	Erec	lo = 15 A, V _{CC} = 300 V, VD = 15 V, L = 690 μ H, Tc = 100°C			-	16	-	μJ
Diode reverse recovery time	Trr				-	62	-	ns
Reverse bias safe operating area	RBSOA	Io = 49 A, V _{CE} = 450 V			Full square			
Short circuit safe operating area	SCSOA	V _{CE} = 400 V, Tc =	= 100°C		4		μs	
Electric current output signal level	ISO	lo = 30 A		-	0.384	0.405	0.427	V
				1			<u>ــــــــــــــــــــــــــــــــــــ</u>	1

Reference voltage is N terminal = V_{SS} terminal voltage unless otherwise specified.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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Notes

1. When the internal protection circuit operates, a Fault signal is turned ON (When the Fault terminal is low level, Fault signal is ON state : output form is open DRAIN) but the Fault signal does not latch. After protection operation ends, it returns automatically within about 18 ms to 80 ms and resumes operation beginning condition. So, after Fault signal detection, set all input signals to OFF (Low) at once. However, the operation of pre-drive power supply low voltage protection (UVLO : with hysteresis about 0.2 V) is as follows.

Upper side :

The gate is turned off and will return to regular operation when recovering to the normal voltage, but the latch will continue till the input signal will turn 'low'.

Lower side :

The gate is turned off and will automatically reset when recovering to normal voltage. It does not depend on input signal voltage.

- 2. When assembling the IPM on the heat sink with M4 type screw, tightening torque range is 0.79 Nm to 1.17 Nm.
- 3. The pre-drive low voltage protection is the feature to protect devices when the pre-driver supply voltage falls due to an operating malfunction.

Pin Assignment

Pin No.	Name	Description	Pin No.	Name	Description
1	VB1	High side floating supply voltage 1	44	Р	Positive bus input voltage
2	VS1	High side floating supply offset voltage	43	Р	Positive bus input voltage
3	-	Without pin	42	Р	Positive bus input voltage
4	VB2	High side floating supply voltage 2	41	-	Without pin
5	VS2	High side floating supply offset voltage	40	Ν	Negative bus input voltage
6	-	Without pin	39	Ν	Negative bus input voltage
7	VB3	High side floating supply voltage 3	38	Ν	Negative bus input voltage
8	VS3	High side floating supply offset voltage	37	-	Without pin
9	-	Without pin	36	U	U-phase output
10	HIN1	Logic input high side driver-Phase1	35	U	U-phase output
11	HIN2	Logic input high side driver-Phase2	34	U	U-phase output
12	HIN3	Logic input high side driver-Phase3	33	-	Without pin
13	LIN1	Logic input low side driver-Phase1	32	V	V-phase output
14	LIN2	Logic input low side driver-Phase2	31	V	V-phase output
15	LIN3	Logic input low side driver-Phase3	30	V	V-phase output
16	FAULT	Fault out (open drain)	29	-	Without pin
17	ISO	Current monitor pin	28	W	W-phase output
18	TH	Thermistor out	27	W	W-phase output
19	VDD	+15 V main supply	26	W	W-phase output
20	VSS	Negative main supply	25	-	Without pin
21	ISD	Over-current protection level setting pin	24	NC	-
22	NC	-	23	NC	-

Block Diagram

